

# NSM80101MT1G

## NPN Transistor with Dual Series Switching Diode

### Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### Typical Applications

- LCD Control Board
- High Speed Switching
- High Voltage Switching

### MAXIMUM RATINGS – PNP TRANSISTOR

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	$V_{CEO}$	80	Vdc
Collector – Base Voltage	$V_{CBO}$	80	Vdc
Emitter – Base Voltage	$V_{EBO}$	6.0	Vdc
Collector Current – Continuous	$I_C$	500	mAdc

### MAXIMUM RATINGS – SWITCHING DIODE

Rating	Symbol	Value	Unit
Reverse Voltage	$V_R$	100	V
Forward Current	$I_F$	200	mA
Non-Repetitive Peak Forward Current (Square Wave, $T_J = 25^\circ\text{C}$ prior to surge) $t < 1 \text{ sec}$ $t = 1 \mu\text{sec}$	$I_{FSM}$	1.0 20	A
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### ESD RATINGS

Rating	Class	Value
Electrostatic Discharge	HBM MM	3A M4 4000 V ≤ Failure < 8000 V Failure > 400 V

### THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	400	mW mW/ $^\circ\text{C}$
Thermal Resistance from Junction-to-Ambient (Note 1)	$R_{\theta JA}$	313	$^\circ\text{C}/\text{W}$
Total Device Dissipation FR-5 Board (Note 2) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	270	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	463	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

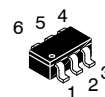
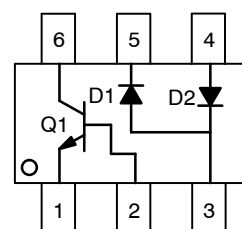
1. FR-5 = 650 mm<sup>2</sup> pad, 2.0 oz Cu.
2. FR-5 = 10 mm<sup>2</sup> pad, 2.0 oz Cu.



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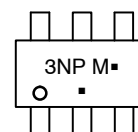
<http://onsemi.com>

## NPN Transistor with Dual Series Switching Diode



SC-74  
CASE 318F

### MARKING DIAGRAM



3NP = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)  
\*Date Code orientation may vary depending upon manufacturing location.

### ORDERING INFORMATION

Device	Package	Shipping†
NSM80101MT1G	SC-74 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NSM80101MT1G

## Q1: NPN TRANSISTOR

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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#### OFF CHARACTERISTICS

Collector – Emitter Breakdown Voltage (Note 3)	$(I_C = 1.0 \text{ mA}, I_B = 0)$	$V_{(BR)CEO}$	80	–	V
Emitter – Base Breakdown Voltage	$(I_E = 100 \text{ } \mu\text{A}, I_C = 0)$	$V_{(BR)EBO}$	6.0	–	V
Collector Cutoff Current	$(V_{CE} = 60 \text{ V}, I_B = 0)$	$I_{CES}$	–	0.1	$\mu\text{A}$
Collector Cutoff Current	$(V_{CB} = 80 \text{ V}, I_E = 0)$	$I_{CBO}$	–	0.1	$\mu\text{A}$

#### ON CHARACTERISTICS (Note 3)

DC Current Gain	$(I_C = 10 \text{ mA}, V_{CE} = 1.0 \text{ V})$	$h_{FE}$	120	–	–
Collector – Emitter Saturation Voltage	$(I_C = 100 \text{ mA}, I_B = 10 \text{ mA})$	$V_{CE(sat)}$	–	0.3	V
Base – Emitter Saturation Voltage	$(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ Vdc})$	$V_{BE(sat)}$	–	1.2	V

#### SMALL – SIGNAL CHARACTERISTICS

Current – Gain – Bandwidth Product	$(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz})$	$f_T$	150	–	MHz
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3. Pulse Test: Pulse Width  $\leq 300 \text{ } \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## D1, D2: SWITCHING DIODE ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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#### OFF CHARACTERISTICS

Reverse Breakdown Voltage		$V_{(BR)}$	75	–	V
Reverse Voltage Leakage Current	$(V_R = 75 \text{ V})$ $(V_R = 20 \text{ V}, T_J = 150^\circ\text{C})$ $(V_R = 75 \text{ V}, T_J = 150^\circ\text{C})$	$I_R$	– – –	1.0 30 100	$\mu\text{A}$
Diode Capacitance	$(V_R = 0 \text{ V}, f = 1.0 \text{ MHz})$	$C_D$	–	2.0	pF
Forward Voltage	$(I_F = 1.0 \text{ mA})$ $(I_F = 10 \text{ mA})$ $(I_F = 50 \text{ mA})$ $(I_F = 150 \text{ mA})$	$V_F$	– – – –	715 855 1000 1250	mV
Reverse Recovery Time	$(I_F = I_R = 10 \text{ mA}, i_{R(REC)} = 1.0 \text{ mA}, R_L = 100 \text{ } \Omega)$	$t_{rr}$	–	6.0	ns
Forward Recovery Voltage	$(I_F = 10 \text{ mA}, t_r = 20 \text{ ns})$	$V_{FR}$	–	1.75	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

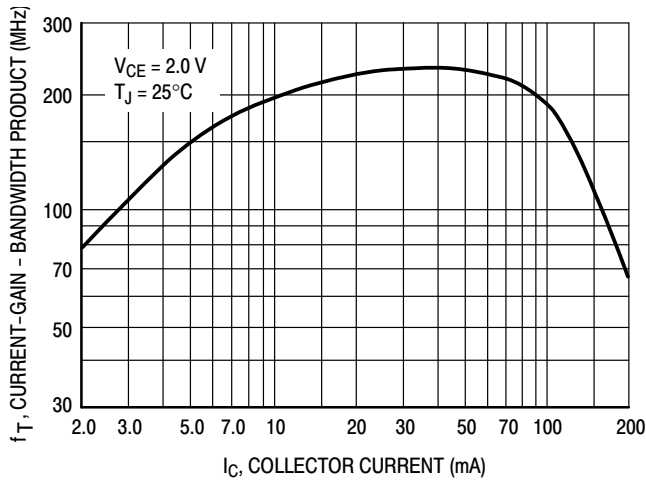


Figure 1. Current-Gain — Bandwidth Product

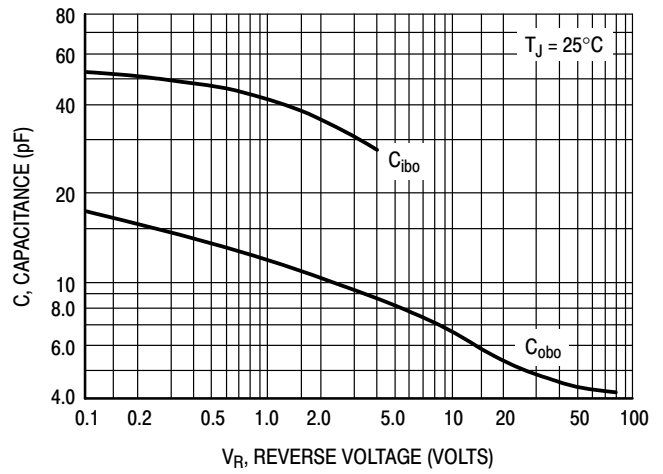


Figure 2. Capacitance

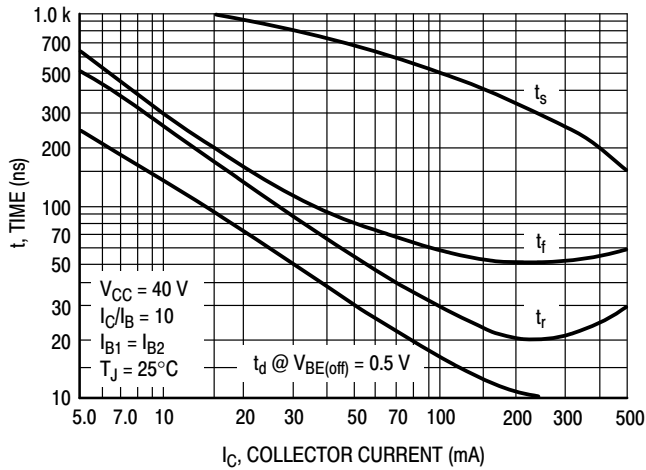


Figure 3. Switching Time

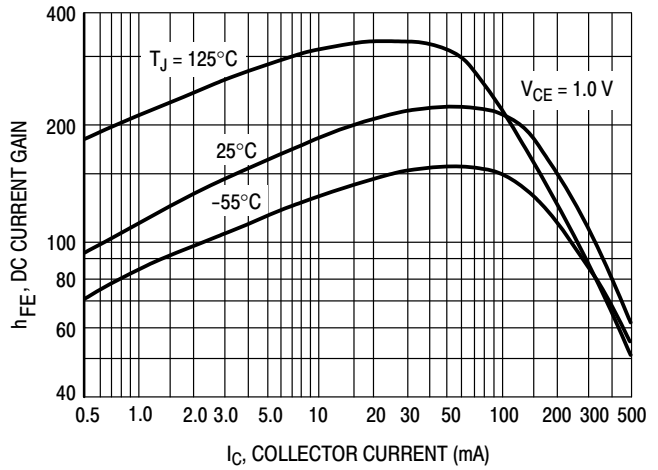


Figure 4. DC Current Gain

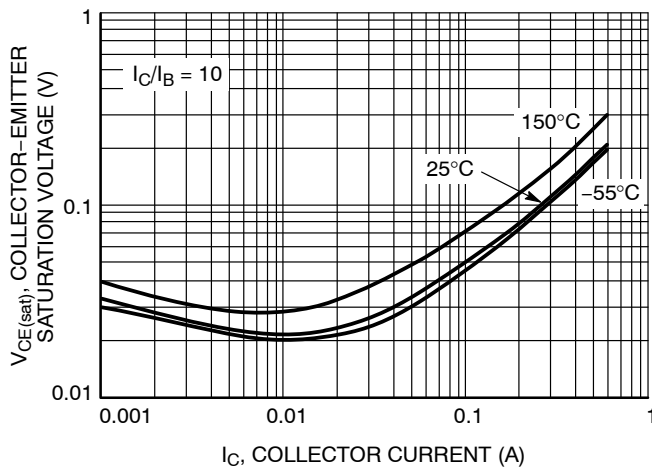


Figure 5. Collector Emitter Saturation Voltage vs. Collector Current

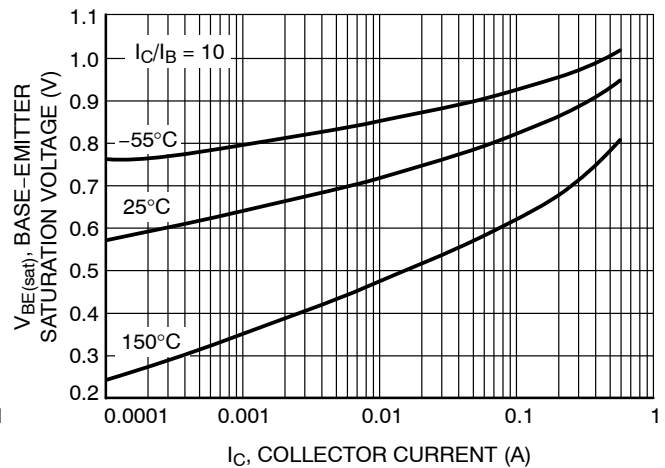


Figure 6. Base Emitter Saturation Voltage vs. Collector Current

TYPICAL CHARACTERISTICS

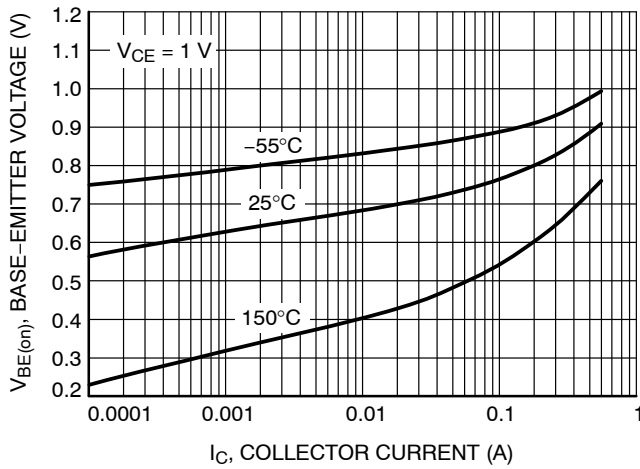


Figure 7. Base Emitter Voltage vs. Collector Current

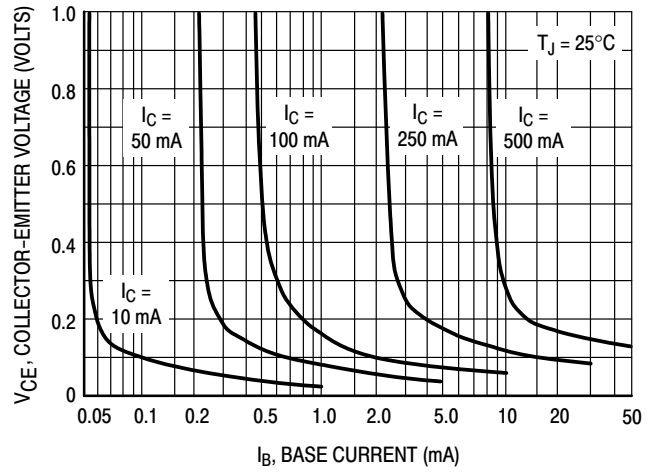


Figure 8. Collector Saturation Region

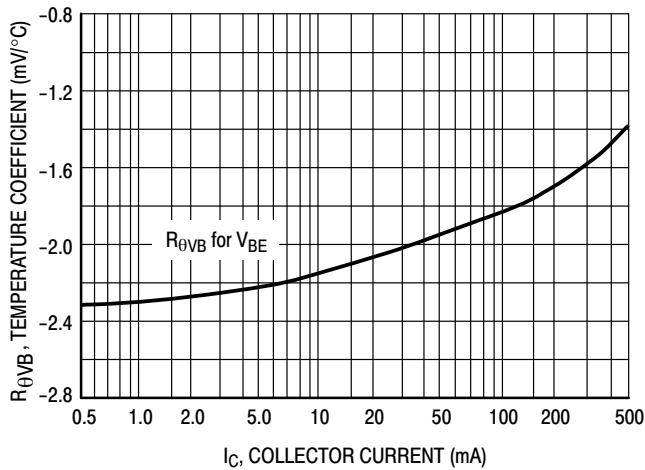


Figure 9. Base-Emitter Temperature Coefficient

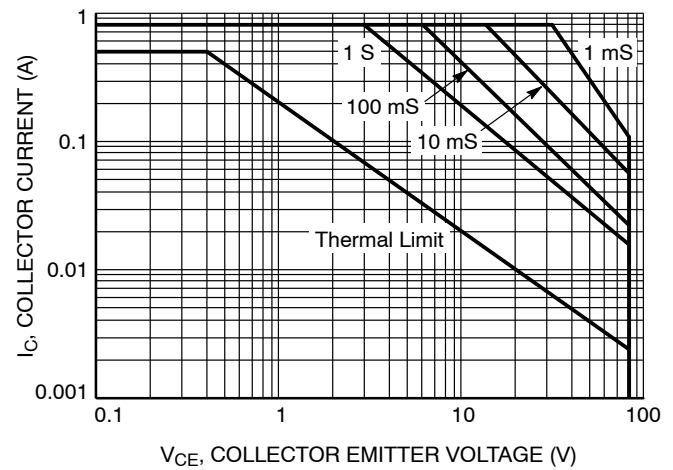


Figure 10. Safe Operating Area

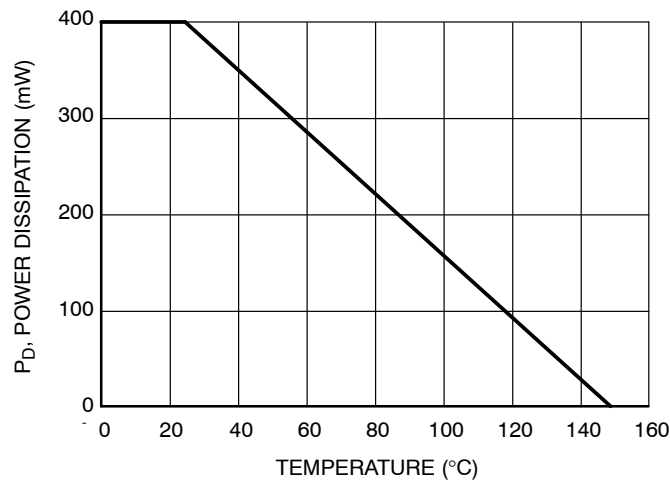


Figure 11. Operating Temperature Derating

TYPICAL CHARACTERISTICS

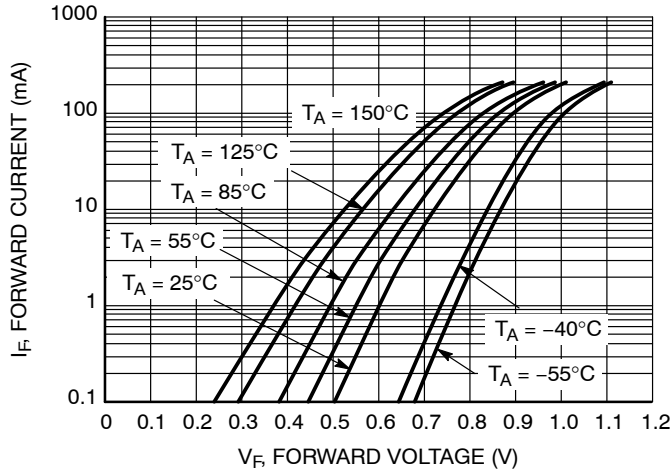


Figure 12. Forward Voltage

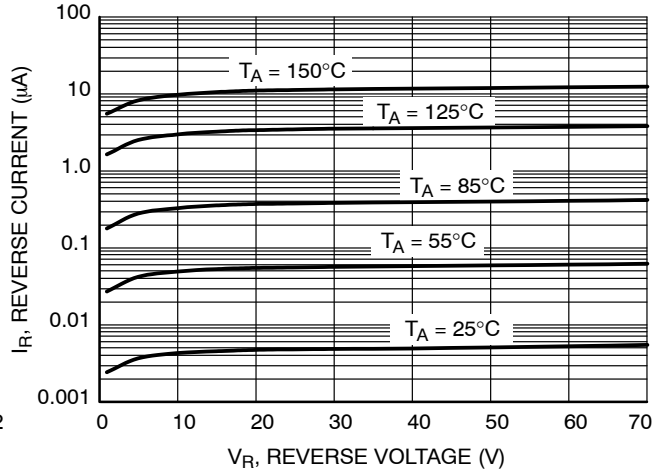


Figure 13. Leakage Current

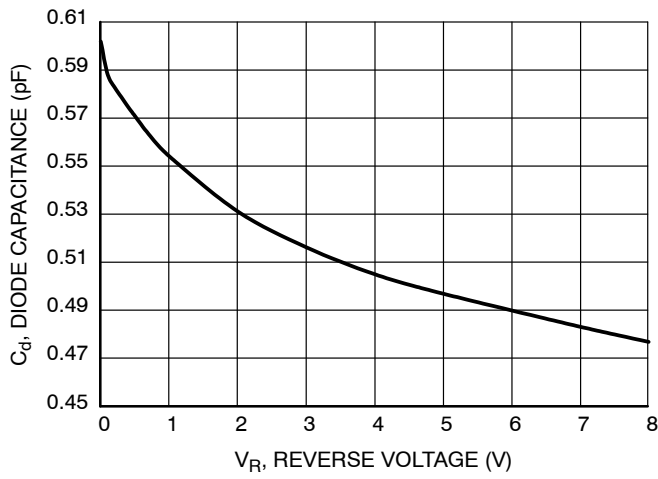


Figure 14. Capacitance

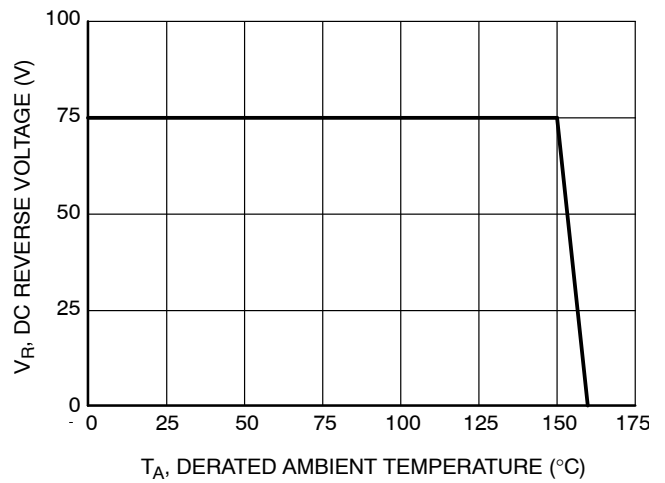
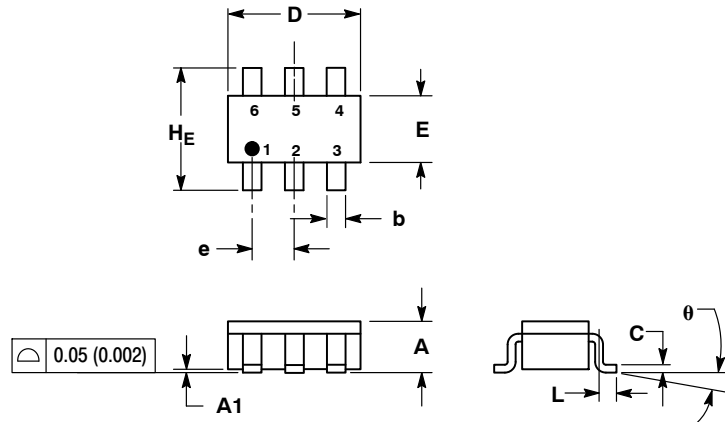


Figure 15. Diode Power Dissipation Curve

# NSM80101MT1G

## PACKAGE DIMENSIONS

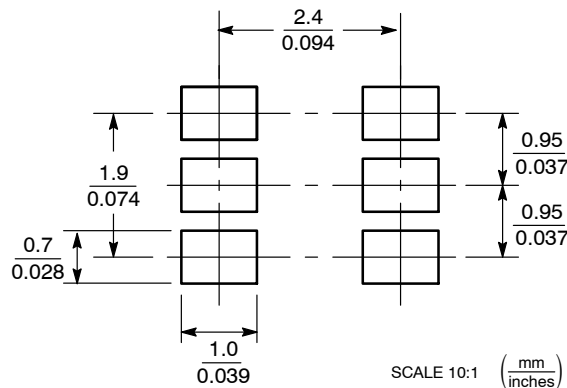
SC-74  
CASE 318F-05  
ISSUE N



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  4. 318F-01, -02, -03 OBSOLETE. NEW STANDARD 318F-04.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
c	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
theta	0°	—	10°	0°	—	10°

## SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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